V20M120C, VI20M120C

Vishay General Semiconductor

# **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.55$  V at  $I_F = 5$  A

### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- HALOGEN Solder dip 275 °C max. 10 s, per JESD 22-B106 FREE
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-220AB and TO-262AA Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker testt

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| <b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)                    |            |                                   |          |           |      |  |  |
|---|------------|-----------------------------------|----------|-----------|------|--|--|
| PARAMETER   |            | SYMBOL                            | V20M120C | VI20M120C | UNIT |  |  |
| Maximum repetitive peak reverse voltage   |            | V <sub>RRM</sub>                  | 12       | 120       |      |  |  |
| Maximum average forward rectified current (fig. 1)  | per device | I <sub>F(AV)</sub>                | 20       |           | А    |  |  |
|   | per diode  |                                   | 10       |           |      |  |  |
| Peak forward surge current 8.3 ms single half sine-w superimposed on rated load per diode | ave        | I <sub>FSM</sub>                  |          | 20        |      |  |  |
| Voltage rate of change (rated $V_R$ )   |            | dV/dt                             | 10       | 000       | V/µs |  |  |
| Operating junction and storage temperature range  |            | T <sub>J</sub> , T <sub>STG</sub> | -40 to   | +175      | °C   |  |  |

### **TMBS**<sup>®</sup> TO-220AB TO-262AA VI20M120C V20M120C PIN 1 O PIN 2 PIN 2 PIN 3 O-CASE PIN 3 O-ĸ

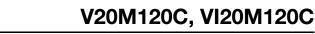
| PRIMARY CHARACTERISTICS |                    |  |  |  |
|-------------------------|--------------------|--|--|--|
| I <sub>F(AV)</sub>      | 2 x 10 A           |  |  |  |
| V <sub>RRM</sub>        | 120 V              |  |  |  |
| I <sub>FSM</sub>        | 120 A              |  |  |  |
| $V_F$ at $I_F = 10$ A   | 0.64 V             |  |  |  |
| T <sub>J</sub> max.     | 175 °C             |  |  |  |
| Package                 | TO-220AB, TO-262AA |  |  |  |
| Diode variations        | Common cathode     |  |  |  |

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RoHS COMPLIANT







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| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted) |                       |                           |                               |      |      |      |  |
|---|-----------------------|---------------------------|-------------------------------|------|------|------|--|
| PARAMETER   | TEST CO               | NDITIONS                  | SYMBOL                        | TYP. | MAX. | UNIT |  |
| Instantaneous forward voltage per diode                                   | I <sub>F</sub> = 5 A  | – T <sub>A</sub> = 25 °C  | V <sub>F</sub> <sup>(1)</sup> | 0.65 | -    | v    |  |
|   | I <sub>F</sub> = 10 A |                           |                               | 0.82 | 0.91 |      |  |
|   | I <sub>F</sub> = 5 A  | – T <sub>A</sub> = 125 °C |                               | 0.55 | -    |      |  |
|   | I <sub>F</sub> = 10 A |                           |                               | 0.64 | 0.72 |      |  |
| Reverse current per diode   | V <sub>R</sub> = 90 V | T <sub>A</sub> = 25 °C    | I <sub>R</sub> <sup>(2)</sup> | 3    | -    | μA   |  |
|   |                       | T <sub>A</sub> = 125 °C   |                               | 1.5  | -    | mA   |  |
|   | $V_{\rm P} = 120 V$   | T <sub>A</sub> = 25 °C    |                               | -    | 700  | μA   |  |
|   |                       | T <sub>A</sub> = 125 °C   |                               | 4    | 25   | mA   |  |

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  5 ms

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |            |                                 |          |           |      |
|--|------------|---------------------------------|----------|-----------|------|
| PARAMETER  |            | SYMBOL                          | V20M120C | VI20M120C | UNIT |
|  | per diode  | В                               | 2.8      |           | °C/W |
| Typical thermal resistance <sup>(1)</sup>                                      | per device | R <sub>θJC</sub>                | 1.6      |           |      |
|  | per device | R <sub>0JA</sub> <sup>(2)</sup> | 45       | 55        |      |

#### Notes

 $^{(1)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient dP<sub>D</sub>/dT<sub>J</sub> < 1/R<sub> $\theta$ JA</sub>

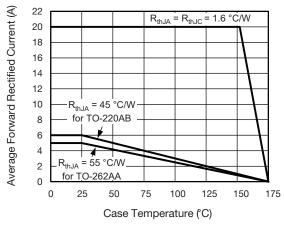
<sup>(2)</sup> Free air, without heatsink

| ORDERING INFORMATION (Example) |                 |                 |              |               |               |  |  |
|--------------------------------|-----------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE                        | PREFERRED P/N   | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |  |
| TO-220AB                       | V20M120C-M3/4W  | 1.88            | 4W           | 50/tube       | Tube          |  |  |
| TO-262AA                       | VI20M120C-M3/4W | 1.45            | 4W           | 50/tube       | Tube          |  |  |



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### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)



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Fig. 1 - Maximum Forward Current Derating Curve

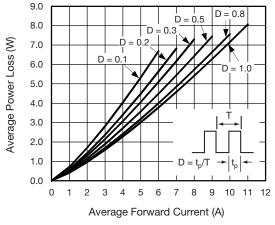


Fig. 2 - Forward Power Loss Characteristics Per Diode

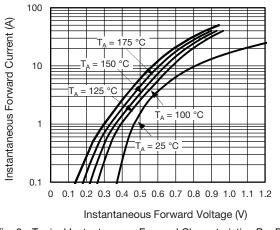
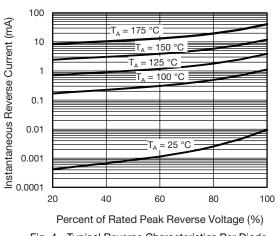


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode





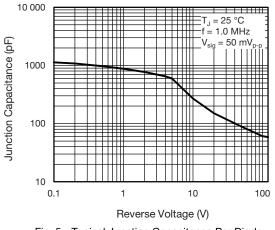
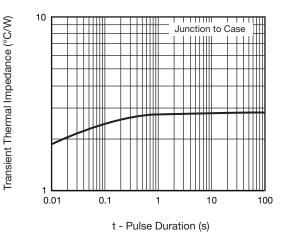
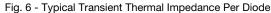


Fig. 5 - Typical Junction Capacitance Per Diode





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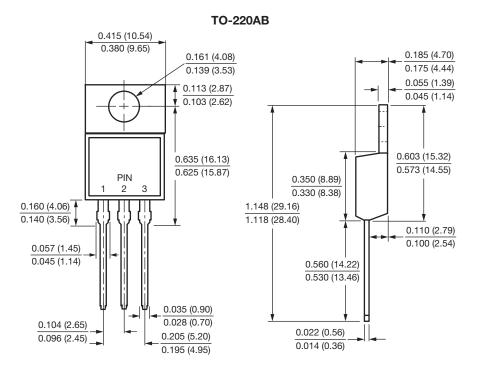
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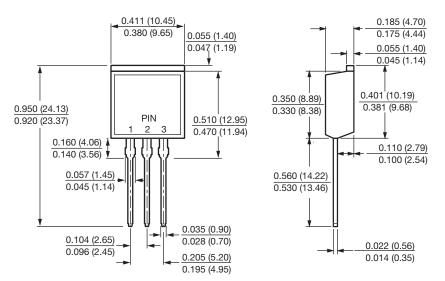
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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



**TO-262AA** 





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